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<b>Form PTO-1449 (Modified)</b>		<b>ATTY DOCKET NO.</b> B-3964 618029-8	<b>U.S. SERIAL NO.</b> 09/768,904
<b>LIST OF PATENTS AND PUBLICATIONS STATEMENT</b>		<b>APPLICANT(S)</b> Lap-Wai CHOW, et al.	
		<b>FILING DATE</b> January 24, 2001	<b>GROUP</b> 2815

**U. S. PATENT DOCUMENTS**

<b>EXAMINER INITIAL</b>	<b>DOCUMENT NUMBER</b>	<b>ISSUE DATE</b>	<b>NAME</b>	<b>CLASS</b>	<b>SUBCLASS</b>	<b>FILING DATE or 102(e) DATE IF APPROPRIATE</b>
JN	3,673,471	6/72	Klein et al.	317	235 R	
	3,946,426	3/76	Sanders	357	71	
	4,017,888	4/77	Christie et al.	357	54	
	4,139,864	2/79	Schulman	358	188	
	4,164,461	8/79	Schilling	204	192 EC	
	4,196,443	4/80	Dingwall	357	68	
	4,267,578	5/81	Vetter	364	709	
	4,291,391	9/81	Chatterjee et al.	365	184	
	4,295,897	10/81	Tubbs et al.	148	1.5	
	4,314,268	2/82	Yoshioka et al.	357	48	
	4,317,273	3/82	Guterman et al.	29	571	
	4,374,454	2/83	Jochems	29	571	
	4,409,434	10/83	Basset et al.	380	265	
	4,435,895	3/84	Parillo	29	571	
	4,471,376	9/84	Morcom et al.	357	71	
	4,581,628	4/86	Miyauchi et al.	357	71	
	4,583,011	4/86	Pechar	307	440	
	4,603,381	7/86	Guttag et al.	364	200	
	4,623,255	11/86	Suszko	356	389	
	4,727,493	2/88	Taylor, Sr.	364	490	



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	4,766,516	8/88	Ozdemir et al.	361	380	
	4,799,096	1/89	Koeppe	357	42	
	4,821,085	4/89	Haken et al.	357	67	
	4,830,974	5/89	Chang et al.	437	34	
	4,939,567	7/90	Kenney	257	383	
	4,975,756	12/90	Haken et al.	357	4.1	
	4,998,151	3/91	Korman et al.	257	328	
	4,962,484	10/90	Takeshima et al.	365	226	
	5,030,796	7/91	Swanson et al.	174	52.2	
	5,050,123	9/91	Castro	365	53	
	5,061,978	10/91	Mizutani et al.	357	30	
	5,065,208	11/91	Shah et al.	357	34	
	5,068,697	11/91	Noda et al.	357	23.5	
	5,070,378	12/91	Yamagata	357	23.5	
	5,101,121	3/92	Sourgen	307	465	
	5,117,276	5/92	Thomas et al.	357	71	
	5,121,089	6/92	Larson et al.	333	107	
	5,121,186	6/92	Wong et al.	257	384	
	5,132,571	7/92	McCollum et al.	307	465.1	
	5,138,197	8/92	Kuwana	307	449	
	5,146,117	9/92	Larson	307	465	
	5,168,340	12/92	Nishimura	357	376	
	5,202,591	4/93	Walden	307	450	
	5,227,649	7/93	Chapman	257	204	
	5,231,299	7/93	Ning et al.	257	316	
	5,302,539	4/94	Haken et al.	437	41	
	5,308,682	5/94	Morikawa	428	195	
	5,309,015	5/94	Kuwata et al.	257	659	
	5,336,624	8/94	Walden	437	34	
	5,341,013	8/94	Koyanagi et al.	257	368	



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	5,354,704	10/94	Yang et al.	437	52	
	5,369,299	11/94	Byrne et al.	257	638	
	5,371,390	12/94	Mohsen	257	209	
	5,376,577	12/94	Roberts et al.	437	52	
	5,384,472	1/95	Yin	257	204	
	5,399,441	3/95	Bearinger et al.	428	689	
	5,441,902	8/95	Hsieh et al.	437	34	
	5,468,990	11/95	Daum	257	632	
	5,475,251	12/95	Kuo et al.	257	316	
	5,506,806	4/96	Fukushima	365	195	
	5,531,018	7/96	Saia et al.	29	622	
	5,539,224	7/96	Ema	257	211	
	5,541,614	7/96	Lam et al.	343	792.5	
	5,571,735	11/96	Mogami et al.	437	41	
	5,576,988	11/96	Kuo et al.	365	185.04	
	5,611,940	3/97	Zettler	73	514.16	
	5,638,946	6/97	Zavracky	200	181	
	5,719,422	2/98	Burr et al.	257	336	
	5,719,430	2/98	Goto	257	403	
	5,721,150	2/98	Pasch	437	46	
	5,838,047	3/99	Yamauchi et al.	257	372	
	5,880,503	3/99	Matsumoto et al.	257	372	
	5,920,097	7/99	Horne	257	368	
	5,973,375	10/99	Baukus et al.	257	399	
	6,046,659	4/00	Loo et al.	333	262	
	6,054,659	4/00	Lee et al.	200	181	
	6,057,520	5/00	Goodwin-Johansson	200	181	
	6,117,762	9/00	Baukus et al.	438	618	
	6,154,388	11/00	Oh	365	185.04	
	6,215,158 B1	4/01	Choi	257	368	



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/	6,294,816 B1	9/01	Baukus et al.	257	368	
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FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	PUBLICATION DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES/NO
	98/21734	5/98	WO			
	00/44012	7/00	WO			
	0 364 769	4/90	EP			
	0 463 373	1/92	EP			
	0 528 302 A1	2/93	EP			
	0 585 601 A1	9/90	EP			
	0 764 985 A2	3/97	EP			
	0 883 184 A2	12/98	EP			
	2486717	1/82	EP			
	58-190064	11/83	JP			
	63 129647 A	6/88	JP			
	02-046762	2/93	JP			
	02-237038	9/90	JP			

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

	Document No. 02237038, dated December 6, 1990, Patent Abstracts of Japan, Vol. 014, No. 550 (E-1009).
	Document No. 63129647, dated Jun. 2, 1988, Patent Abstracts of Japan, Vol. 012, No. 385 (E-668), Oct. 14, 1998.
	Patent Abstracts of Japan, vol. 016, No. 197 (p-1350) May 12, 1992 & JP-A-40 28 092 (Toshiba Corp), abstract.
	Fredericksen, T.M., "A Multiple-Layer-Metal CMOS Process," <i>Intuitive CMOS Electronics</i> , Revised Edition, Section 5.6, pp. 134-146 (1989).
	Hodges and Jackson, <i>Analysis and Design of Digital Integrated Circuits</i> , 2nd edition, McGraw-Hill, p. 353 (1988).
	Larson, L.E., et al., "Microactuators for GaAs-based Microwave Integrated Circuits," <i>IEEE</i> , pp. 743-746 (1991).



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	Lee, "Engineering a Device for Electron-beam Probing," <i>IEEE Design and Test of Computers</i> , pp. 36-49 (1989).
	Sze, S.M., ed. <i>VLSI Technology</i> , McGraw-Hill, pp. 99, 447, and 461-465 (1983).
	Sze, S.M., ed., "Silicides for Gates and Interconnections," <i>VLSI Technology</i> , McGraw-Hill, pp. 372-380 (1983).

EXAMINER	DATE CONSIDERED
JOSEPH NGUYEN	10/31/02

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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